



SILICON RFIC LOW CURRENT AMPLIFIER FOR MOBILE COMMUNICATIONS

UPC8178TB

FEATURES

- **LOW CURRENT CONSUMPTION**
I_{CC} = 1.9 mA TYP @ V_{CC} = 3.0 V
- **SUPPLY VOLTAGE:**
V_{CC} = 2.4 to 3.3 V
- **EXCELLENT ISOLATION:**
ISOL = 39 dB TYP @ f = 1.0 GHz
ISOL = 40 dB TYP @ f = 1.9 GHz
ISOL = 38 dB TYP @ f = 2.4 GHz
- **POWER GAIN:**
GP = 11.0 dB TYP @ f = 1.0 GHz
GP = 11.5 dB TYP @ f = 1.9 GHz
GP = 11.5 dB TYP @ f = 2.4 GHz
- **OPERATING FREQUENCY:**
0.1 to 2.4 GHz (Output port LC matching)
- **1 dB GAIN COMPRESSION OUTPUT POWER:**
P_{O(1 dB)} = -4.0 dBm TYP @ f = 1.0 GHz
P_{O(1 dB)} = -7.0 dBm TYP @ f = 1.9 GHz
P_{O(1 dB)} = -7.5 dBm TYP @ f = 2.4 GHz
- **HIGH-DENSITY SURFACE MOUNTING:**
6-pin super minimold package (2.0 x 1.25 x 0.9 mm)
- **LOW WEIGHT:**
7 mg (Standard Value)

APPLICATIONS

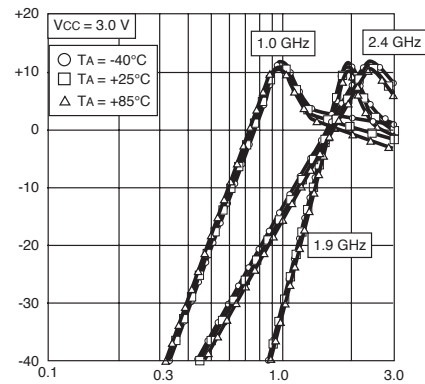
- Buffer Amplifiers on 0.1 to 2.4 GHz mobile communications system

ELECTRICAL CHARACTERISTICS

(T_A = 25°C, V_{CC} = V_{OUT} = 3.0 V, Z_S = Z_L = 50 Ω, at LC matched frequency unless otherwise specified))

PART NUMBER PACKAGE OUTLINE			UPC8178TB S06			
SYMBOLS	PARAMETERS AND CONDITIONS ¹		UNITS	MIN	TYP	MAX
I _{CC}	Circuit Current (no signal)		mA	1.4	1.9	2.4
GP	Power Gain	f = 1.0 GHz	dB	9.0	11.0	13.0
		f = 1.9 GHz	dB	9.0	11.5	13.5
		f = 2.4 GHz	dB	9.0	11.5	13.5
ISOL	Isolation	f = 1.0 GHz	dB	34	39	–
		f = 1.9 GHz	dB	35	40	–
		f = 2.4 GHz	dB	33	38	–
P _{O(1dB)}	1 dB Gain Compression Output Power	f = 1.0 GHz	dBm	-8.0	-4.0	–
		f = 1.9 GHz	dBm	-11.0	-7.0	–
		f = 2.4 GHz	dBm	-11.5	-7.5	–
NF	Noise Figure	f = 1.0 GHz	dB	–	5.5	7.0
		f = 1.9 GHz	dB	–	5.5	7.0
		f = 2.4 GHz	dB	–	5.5	7.0
RL _{in}	Input Return Loss	f = 1.0 GHz	dB	4	7	–
		f = 1.9 GHz	dB	5	8	–
		f = 2.4 GHz	dB	6.5	9.5	–

POWER GAIN vs. FREQUENCY



DESCRIPTION

The UPC8178TB is a silicon monolithic integrated circuit designed as an amplifier for mobile communications. This IC can realize low current consumption with an external chip inductor which cannot be realized on an internal 50 Ω wideband matched IC. This low current amplifier operates on 3.0 V. This device is manufactured using NEC's 30 GHz f_{max} UHS0 (Ultra High Speed Process) silicon bipolar process which uses direct silicon nitride passivation film and gold electrodes. These materials can protect the chip surface from pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

UPC8178TB

ABSOLUTE MAXIMUM RATINGS¹

(T_A = +25°C unless otherwise specified)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V _{CC}	Supply Voltage ²	V	3.6
I _{CC}	Circuit Current	mA	15
P _D	Power Dissipation ³	mW	270
T _A	Operating Ambient Temperature	°C	-40 to +85
T _{STG}	Storage Temperature	°C	-55 to +150
P _{IN}	Input Power	dBm	+5

Notes:

1. Operation in excess of any one of these conditions may result in permanent damage.
2. Pins 4 and 6.
3. Mounted on a double-sided copper clad 50x50x1.6 mm epoxy glass PWB, T_A = +85°C.

RECOMMENDED OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
V _{CC}	Supply Voltage ¹	V	2.4	3.0	3.3
T _A	Operating Ambient Temperature	°C	-40	+25	+85

Note:

1. Same voltage applied to pins 4 and 6.

SERIES PRODUCTS¹ (T_A = +25°C, V_{CC} = V_{out} = 3.0 V, Z_S = Z_L = 50 Ω)

Parameter Part No.	I _{CC} (mA)	1.0 GHz output port matching frequency			1.66 GHz output port matching frequency			1.9 GHz output port matching frequency			2.4 GHz output port matching frequency			Marking
		GP (dB)	ISOL (dB)	Po(1 dB) (dBm)	GP (dB)	ISOL (dB)	Po(1 dB) (dBm)	GP (dB)	ISOL (dB)	Po(1 dB) (dBm)	GP (dB)	ISOL (dB)	Po(1 dB) (dBm)	
UPC8178TB	1.9	11	39	-4.0	-	-	-	11.5	40	-7.0	11.5	38	-7.5	C3B
UPC8179TB	4.0	13.5	44	+3.0	-	-	-	15.5	42	+1.5	15.5	41	+1.0	C3C
UPC8128TB	2.8	12.5	39	-4.0	13	39	-4.0	13	37	-4.0	-	-	-	C2P
UPC8151TB	4.2	12.5	38	+2.5	15	36	+1.5	15	34	+0.5	-	-	-	C2U
UPC8152TB	5.6	23	40	-4.5	19.5	38	-8.5	17.5	35	-8.5	-	-	-	C2V

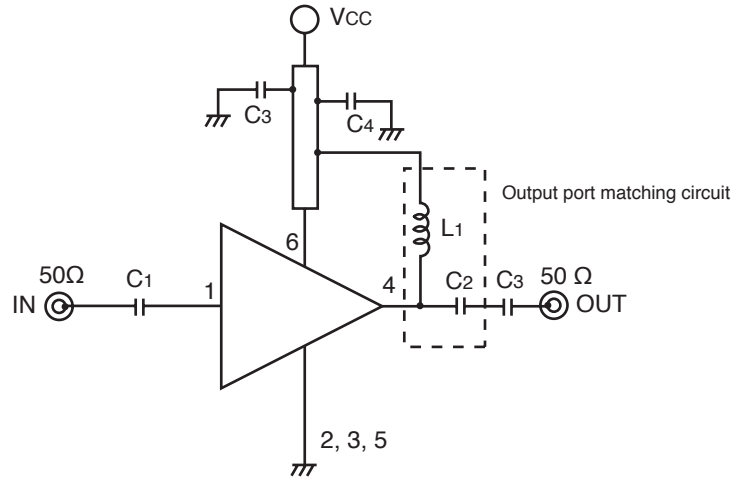
Note:

1. Typical performance.

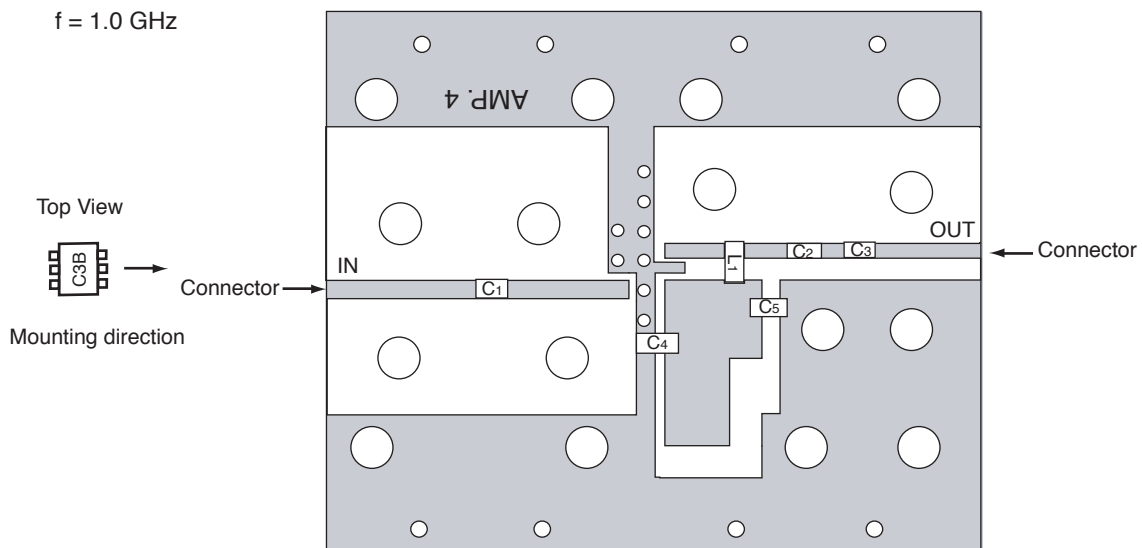
PIN FUNCTIONS (Pin Voltage is measured at V_{CC} = 3.0 V)

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V)	Function and Applications	Internal Equivalent Circuit
1	Input	-	0.91	Signal input pin. An internal matching circuit, configured with resistors, enables a 50 Ω connection over a wide band. This pin must be coupled to the signal source with the capacitor for DC out.	
2 3 5	GND	0	-	Ground pin. This pin should be connected to the system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with a wide ground pattern to decrease impedance difference.	
4	Output	Voltage same as V _{CC} through external inductor	-	Signal output pin. This pin is designed as the collector output. Due to the high impedance output, this pin should be externally equipped with LC matching circuit to next stage. For L, a size 1005 chip inductor can be used.	
6	V _{CC}	2.4 to 3.3	-	Power supply pin. This pin should be externally equipped with a bypass capacitor to minimize its impedance.	

TEST CIRCUIT 1 (f = 1.0 GHz)



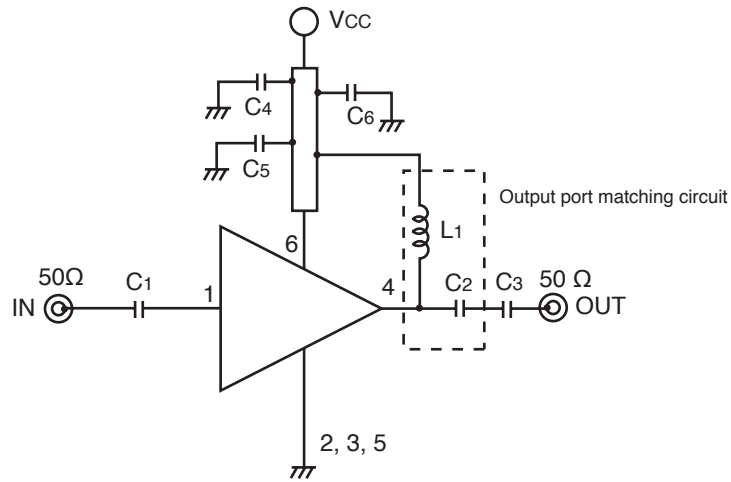
EXAMPLE OF TEST CIRCUIT 1 ASSEMBLED ON EVALUATION BOARD



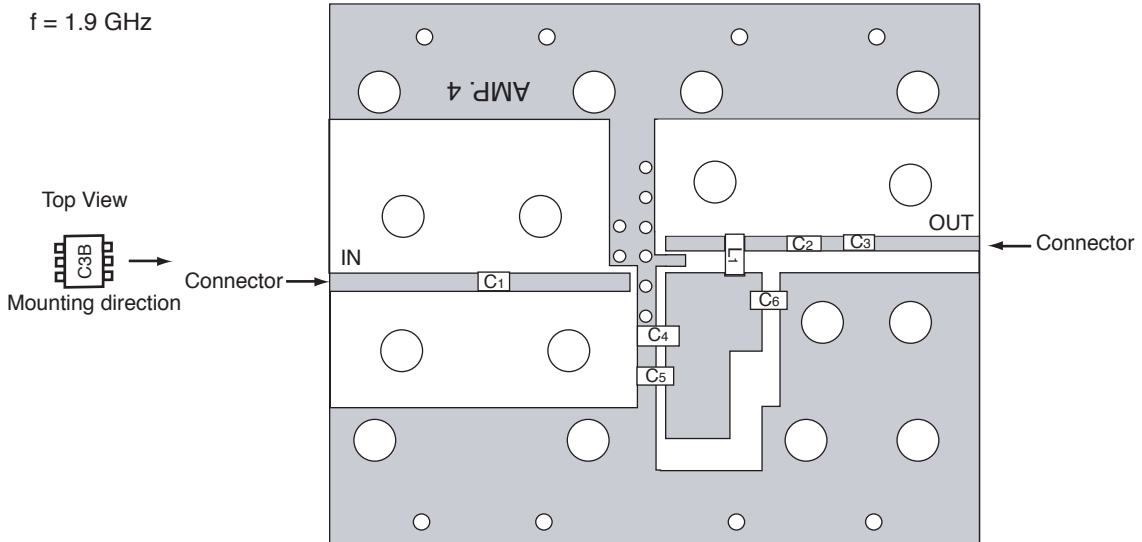
COMPONENT LIST

	1.0 GHz Output Port Matching
C1, C3, C5	1000 pF
C2	0.75 pF
C4	10 pF
L1	12 nH

TEST CIRCUIT 2 (f = 1.9 GHz)



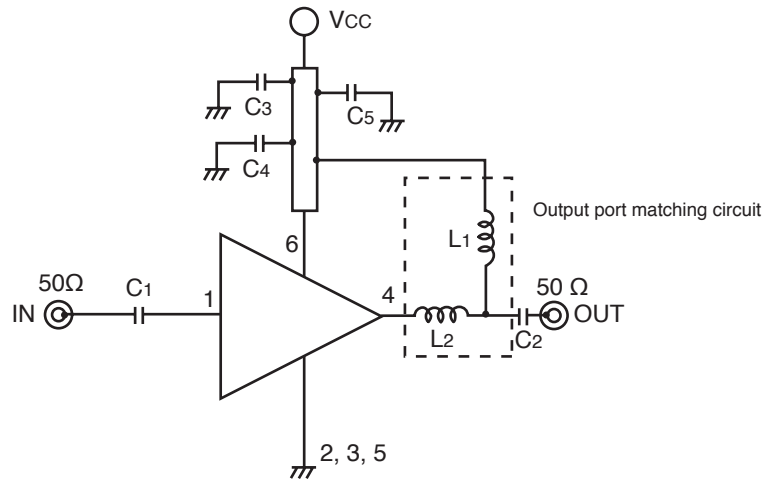
EXAMPLE OF TEST CIRCUIT 2 ASSEMBLED ON EVALUATION BOARD



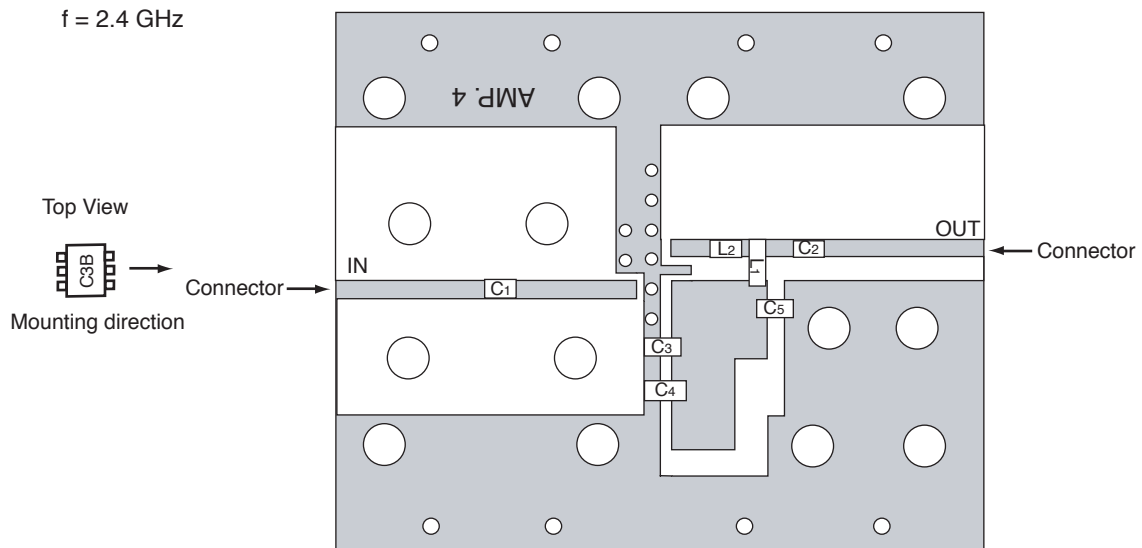
COMPONENT LIST

	1.9 GHz Output Port Matching
C1, C3, C5, C6	1000 pF
C2	0.5 pF
C4	10 pF
L1	3.9 nH

TEST CIRCUIT 3 (f = 2.4 GHz)



EXAMPLE OF TEST CIRCUIT 3 ASSEMBLED ON EVALUATION BOARD



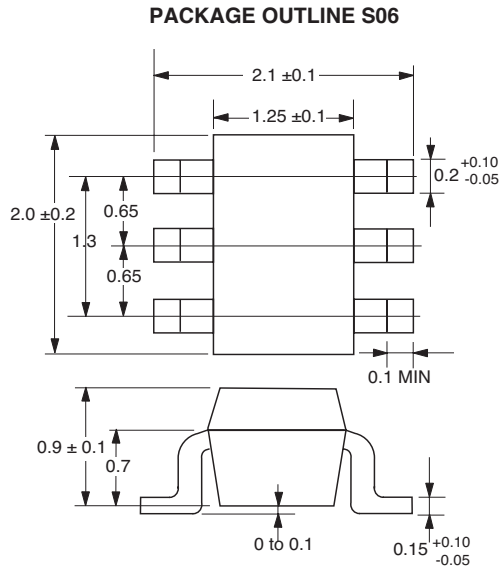
COMPONENT LIST

	2.4 GHz Output Port Matching
C1, C3, C4, C5	1000 pF
C3	10 pF
L1	1.8 nH
L2	2.7 nH

NOTES:

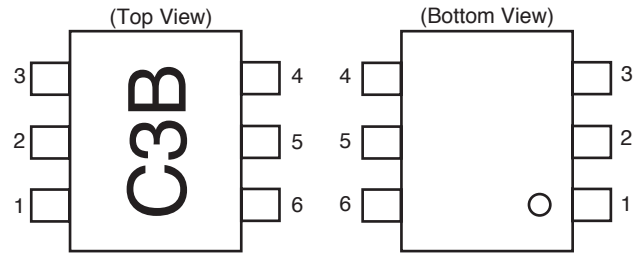
1. 42 x 35 x 0.4 mm double sided copper clad polyimide board.
2. Solder plated on pattern.
3. Back side: GND pattern.
4. ○ Through holes.

OUTLINE DIMENSIONS (Units in mm)



Note:
 All dimensions are typical unless otherwise specified.

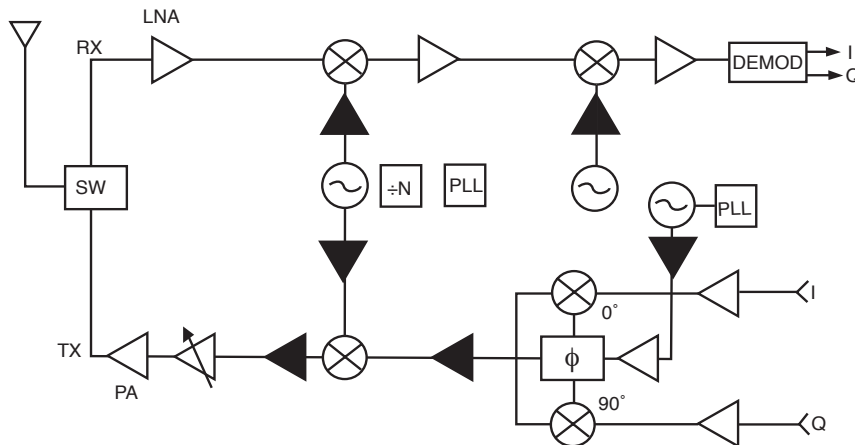
PIN CONNECTIONS



PIN NO.	PIN NAME
1	Input
2	GND
3	GND
4	Output
5	GND
6	Vcc

SYSTEM APPLICATION EXAMPLE

Location examples in digital cellular



ORDERING INFORMATION

Part Number	Quantity
UPC8178TB-E3-A	3 K pcs/reel

Life Support Applications

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Note: Embossed tape, 8 mm wide. Pins 1, 2 and 3 face the tape perforation side.

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06/20/2001

Subject: Compliance with EU Directives

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CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

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Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
		-A	-AZ
Lead (Pb)	< 1000 PPM	Not Detected	(*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

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